Diode Semiconductor Device - Page 1 of 1



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Inclosure	Matorial
inclosure	material:

Glass

Overall Length:

0.250 inches

Overall Diameter:

0.150 inches

Mounting Method:

Terminal

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

200.0 breakdown voltage, dc

Current Rating Per Characteristic:

1.00 amperes source cutoff current preset

Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius ambient air

Test Data Document:

98230-0n228031-1 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,

etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

2 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A110a0